



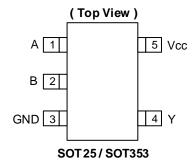
SINGLE 2-INPUT POSITIVE NOR GATE

Description

The 74AHC1G02Q is an automotive compliant single, two-input positive NOR gate with a standard push-pull output. The device is designed for operation with a power supply range of 2.0V to 5.5V. The gate performs the positive Boolean function:

$$Y = \overline{A + B} \text{ or } Y = \overline{A} \bullet \overline{B}$$

Pin Assignments



Features

- Grade 1 Ambient Temperature Operation: -40°C to +125°C
- Supply Voltage Range from 2.0V to 5.5V
- ±8mA Output Drive at 4.5V
- CMOS Low-Power Consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time
- Inputs not Limited by Vcc
- Balanced Propagation Delays
- Balanced Drive Capability
- ESD Protection Tested per AEC-Q100
- Exceeds 2000-V Human Body Model (AEC-Q100-002)
- Exceeds 1000-V Charged Device Model (AEC-Q100-011)
- Latch-Up Exceeds 100mA (AEC-Q100-004)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The 74AHC1G02Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Applications

- General Purpose Logic
- Wide Array of Products, such as:
 - Automotive Applications within Grade 1 Temperature Range
 - Industrial Computing/Controls/Automation
 - High Reliability Networking/Communications
 - Industrial/Agricultural Equipment

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Pin Descriptions

Pin Name	Description
Α	Data Input
В	Data Input
GND	Ground
Y	Data Output
Vcc	Supply Voltage

Logic Diagram



Function Table

Inp	Output	
Α	В	Υ
Н	Х	L
Х	Н	L
L	L	Н

Absolute Maximum Ratings (Notes 4 & 5)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
Vcc	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to Vcc + 0.5	V
lıĸ	Input Clamp Current V _I < 0	-20	mA
Іок	Output Clamp Current (Vo < 0 or Vo > Vcc)	±20	mA
lo	Continuous Output Current (Vo = 0 to Vcc)	±25	mA
Icc	Continuous Current Through Vcc	75	mA
IGND	Continuous Current Through GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
PD	Total Power Dissipation (Note 6)	250	mW

Notes:

^{4.} Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should

^{5.} Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.

6. This will need to be derated at higher operating temperatures to prevent exceeding maximum T_J. Refer to package thermal characteristics section.



Recommended Operating Conditions (Note 7)

Symbol		Parameter	Min	Max	Unit	
Vcc	Operating Voltage	_	2	5.5	V	
		Vcc = 2V	1.5	_		
VIH	High-Level Input Voltage	Vcc = 3V	2.1	_	V	
		Vcc = 5.5V	3.85	_		
		Vcc = 2V	_	0.5		
VIL	Low-Level Input Voltage	Vcc = 3V	_	0.9	V	
		Vcc = 5.5V	_	1.65		
Vı	Input Voltage		0	5.5	V	
Vo	Output Voltage		0	Vcc	V	
		Vcc = 2V	_	-50	μA	
Іон	High-Level Output Current	$VCC = 3.3V \pm 0.3V$	_	-4	1	
		$V_{CC} = 5V \pm 0.5V$	_	-8	mA	
		Vcc = 2V	_	50	μA	
loL	Low-Level Output Current	$V_{CC} = 3.3V \pm 0.3V$	_	4	A	
		$V_{CC} = 5V \pm 0.5V$	_	8	mA	
A4/A)/	Input Transition Rise or Fall	$V_{CC} = 3.3V \pm 0.3V$	_	100		
Δt/ΔV	Rate	$V_{CC} = 5V \pm 0.5V$		20	ns/V	
TA	Ambient Temperature	_	-40	+125	°C	

Note:

Electrical Characteristics (All typical values are at $V_{CC} = 3.3V$, $T_A = +25$ °C)

0	B	Tank On will discuss	V		+25°C		-40°C to	o +85°C	-40°C to	+125°C	1124	
Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit	
		VI = VIH Or VIL	2V	1.9	2	_	1.9	_	1.9	_		
		IOH = -50µA	3V	2.9	3	_	2.9	_	2.9	_		
	High Level	ΙΟΗ = -30μΑ	4.5V	4.4	4.5	_	4.4	_	4.4	_		
Vон	Output Voltage	VI = VIH OR VIL IOH = -4mA	3V	2.58	_	-	2.48	_	2.40	_	V	
		$V_I = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -8\text{mA}$	4.5V	3.94	_	l	3.80	_	3.70	_		
		M M M	2V	_	_	0.1	1	0.1	1	0.1		
		VI = VIH OF VIL		3V	_	_	0.1	_	0.1	_	0.1	
	Low Level Output	I _{OL} = 50μA	4.5V	_	_	0.1	_	0.1	_	0.1		
Vol	Voltage	VI = VIH OR VIL IOL = 4mA	3V	_	_	0.36	_	0.44	_	0.55	V	
		VI = VIH OR VIL IOL = 8mA	4.5V	_	_	0.36	_	0.44	_	0.55		
l ₁	Input Current	V _I = 5.5V or GND	0 to 5.5V	_	_	±0.1	_	±1	_	±2	μΑ	
Icc	Supply Current	V _I = 5.5V or GND I _O = 0	5.5V	_	_	1	1	10	-	40	μΑ	
Сі	Input Capacitance	V _I = V _{CC} or GND	5.5V	_	1.5	10	_	10	_	10	pF	

^{7.} Unused inputs should be held at $V_{\text{\footnotesize CC}}$ or Ground.



Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit
0	Thermal Resistance	SOT25	Note 0	1	184	1	9044
θ JA	Junction-to-Ambient	SOT353	Note 8	-	385	1	°C/W
0	Thermal Resistance	SOT25	Nata 0	_	62	_	0044
θυς	Junction-to-Case	SOT353	Note 8		164	1	°C/W

Note: 8. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

Switching Characteristics

 $Vcc = 3.3V \pm 0.3V$ (See Figure 1)

Parameter	From	То	Test	+25°C		-40°C to +85°C -40°C to +125°C				Unit	
	(Input)	(Output)	Conditions	Min	Тур	Max	Min	Max	Min	Max	
	A D	V	C _L = 15pF	1.0	4.4	7.9	1.0	9.5	1.0	10.5	ns
tPD	A or B	Y	C _L = 50pF	1.0	6.3	11.4	1.0	13.0	1.0	14.5	ns

Vcc = 5V ± 0.5V (See Figure 1)

Parameter	From	То	Test		+25°C		-40°C to +85°C		-40°C to +125°C		Unit
	(Input)	(Output)	Conditions	Min	Тур	Max	Min	Max	Min	Max	
4	A = = D	V	C _L = 15pF	1.0	3.2	5.5	1.0	6.5	1.0	7.0	ns
tPD	A or B	Y	C _L = 50pF	1.0	4.6	7.5	1.0	8.5	1.0	9.5	ns

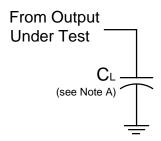
Operating Characteristics

 $T_A = +25$ °C

Parameter		Test Conditions	V _{CC} = 5V Tvp	Unit
CPD	Power Dissipation Capacitance	f = 1MHz No Load	10	pF



Measurement Information



Vcc	In	puts	V _M	C∟
VCC	Vı	t _R /t _F	V WI	OL
3.3V±0.3V	Vcc	≤3ns	Vcc/2	15pF
5V±0.5V	Vcc	≤3ns	Vcc/2	15pF
3.3V±0.3V	Vcc	≤3ns	Vcc/2	50pF
5V±0.5V	Vcc	≤3ns	Vcc/2	50pF

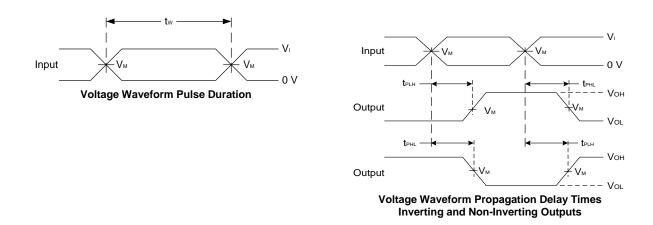


Figure 1. Load Circuit and Voltage Waveforms

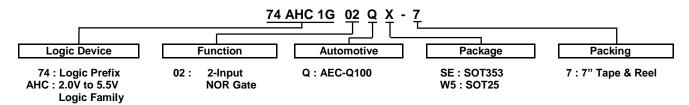
A. Includes test lead and test apparatus capacitance. Notes:

- B. All pulses are supplied at pulse repetition rate ≤ 1MHz.
 C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD}.



1G: One Gate

Ordering Information (Note 9)



Part Number	Package	Package	Package Size	7" Tape	7" Tape and Reel	
Fait Number	Code	(Notes 10 & 11)	Fackage Size	Quantity	Part Number Suffix	
74AHC1G02QSE-7	SE	SOT353	2.15mm × 2.1mm × 1.1mm 0.65mm lead pitch	3000/Tape & Reel	-7	
74AHC1G02QW5-7	W5	SOT25	3.0 mm \times 2.8 mm \times 1.2 mm 0.95 mm lead pitch	3000/Tape & Reel	-7	

Notes: 9. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

10. Pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html.

11. The taping orientation is located on our website at https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf.

Marking Information

(Top View)

XXX YWX 1 2 3 $\begin{array}{c} \underline{XXX} : & \text{Identification Code} \\ \underline{Y} & : & \text{Year } 0{\sim}9 \end{array}$

W : Week: A~Z 1~26 week a~z 27~52 week

z represents week 52 and 53

X : A~ Z: Internal Code

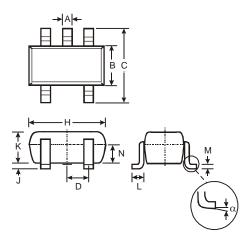
SOT 25 / SOT 353

Part Number	Package	Identification Code
74AHC1G02QW5-7	SOT25	YSQ
74AHC1G02QSE-7	SOT353	YSQ



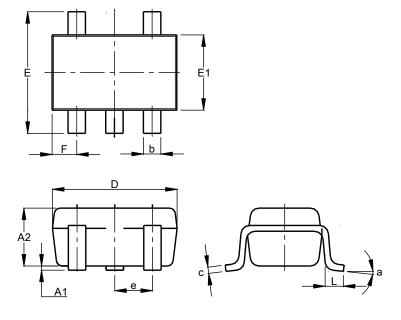
Package Outline Dimensions

(1) Package Type: SOT25



SOT25					
Dim	Min	Max	Тур		
Α	0.35	0.50	0.38		
В	1.50	1.70	1.60		
С	2.70	3.00	2.80		
D		-	0.95		
Н	2.90	3.10	3.00		
J	0.013	0.10	0.05		
K	1.00	1.30	1.10		
L	0.35	0.55	0.40		
M	0.10	0.20	0.15		
N	0.70	0.80	0.75		
α	0°	8°	-		
All Dimensions in mm					

(2) Package Type: SOT353



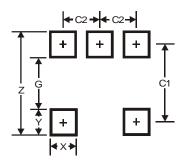
SOT353					
Dim	Min	Max	Тур		
A1	0.00	0.10	0.05		
A2	0.90	1.00	0.95		
b	0.10	0.30	0.25		
С	0.10	0.22	0.11		
D	1.80	2.20	2.15		
Е	2.00	2.20	2.10		
E1	1.15	1.35	1.30		
е	0.650 BSC				
F	0.40	0.45	0.425		
L	0.25	0.40	0.30		
а	0°	8°			
All Dimensions in mm					



Suggested Pad Layout

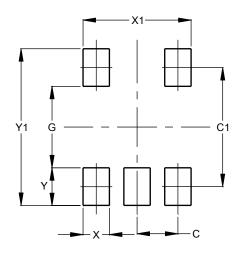
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



Dimensions	Value	
Z	3.20	
G	1.60	
Х	0.55	
Y	0.80	
C1	2.40	
C2	0.95	

(2) Package Type: SOT353



Dimensions	Value (in mm)	
С	0.650	
C1	1.900	
G	1.300	
Х	0.420	
X1	1.720	
Υ	0.600	
Y1	2.500	

Mechanical Data

SOT25

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208@3
- Weight: 0.0158 grams (Approximate)

SOT353

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.0064 grams (Approximate)



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NLV27WZ17DFT2G NLV74HC02ADR2G 74HC32S14-13 74LS133 M38510/30402BDA 74LVC1G86Z-7 74LVC2G08RA3-7

NLV74HC08ADTR2G NLV74HC14ADR2G NLV74HC20ADR2G NLX2G86MUTCG 5962-8973601DA 74LVC2G02HD4-7

NLU1G08AMUTCG NLU1G00AMUTCG 74LVC2G32RA3-7 74LVC2G00HD4-7 NL17SG02P5T5G 74LVC2G00HK3-7

74LVC2G86HK3-7 NLX1G99DMUTWG NLVVHC1G00DFT2G NLVHC1G08DFT2G NLV7SZ57DFT2G NLV74VHC04DTR2G

NLV27WZ86USG NLU1G86CMUTCG NLU1G08CMUTCG NL17SZ32P5T5G NL17SZ00P5T5G NL17SH02P5T5G 74AUP2G00RA3-7

NLVVHC1GT00DFT2G NLV74HC02ADTR2G NLX1G332CMUTCG NL17SG86P5T5G